

Description

The μ PD27C4001 is a 4,194,304-bit ultraviolet erasable EPROM fabricated with double-polysilicon CMOS technology for a substantial savings in both operating and standby power. The device is organized as 524,288 words by 8 bits and operates from a single +5-volt power supply.

The μ PD27C 4001 has a single-location programming feature, three-state outputs, and fully TTL-compatible inputs and outputs. It also has a program voltage (V_{PP}) of 12.5 volts and is available in a 32-pin cerdip with quartz window.

Features

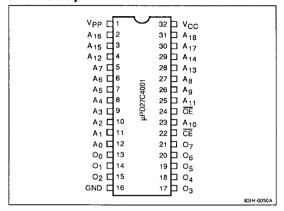
- □ 524,288-word by 8-bit organization
- Ultraviolet erasable and electrically programmable
- High-speed programming
- Low power dissipation
 - 30 mA (active)
 - 100 µA (standby)
- □ TTL-compatible I/O for reading and programming
- □ Single + 5-volt power supply
- Double-polysilicon CMOS technology
- 32-pin cerdip packaging with a quartz window
- JEDEC-compatible pinout

Ordering Information

Part Number	Access Time (max)	Package			
μPD27C4001DZ-15	150 ns	32-pin cerdip with			
DZ-17	170 ns	quartz window			
DZ-20	200 ns	-			

Pin Configuration

32-Pin Cerdip



Pin Identification

Symbol	Function	
A ₀ - A ₁₈	Address inputs	
00 - 07	Data outputs	
CE	Chip enable	
ŌĒ	Output enable	
GND	Ground	
Vcc	+5-volt power supply	
V _{PP}	Program voltage	



Absolute Maximum Ratings

Power supply voltage, V _{CC}	-0.6 to +7.0 V
Input voltage, V _{IN}	-0.6 to V _{CC} + 0.3 V
Input voltage, A ₉	-0.6 to +13.5 V
Output voltage, V _{OUT}	-0.6 to +7.0 V
Operating temperature, TOPR	−10 to +80°C
Storage temperature, T _{STG}	-65 to + 125°C
Program voltage, V _{PP}	-0.6 to +13.5 V
Provide the second	

Exposure to Absolute Maximum Ratings for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The device should be operated within the limits specified under DC and AC Characteristics.

Capacitance

 $T_A = 25$ °C; f = 1 MHz; V_{IN} and $V_{OUT} = 0$ V

Parameter	Symbol	Max	Тур	Unit
Input capacitance	C _{IN}	14		pF
Output capacitance	C _{OUT}	16		рF

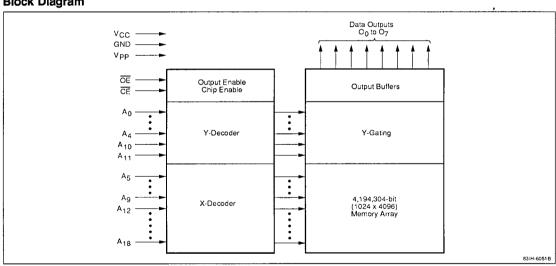
Truth Table

Function	otion CE OE V _{PP}		Vcc	Outputs	
Read	V _{IL}	V _{IL}	+5.0 V	+5.0 V	D _{OUT}
Output disable	V _{IL}	V _{IH}	+5.0 V	+5.0 V	High-Z
Standby	V _{IH}	Х	+5.0 V	+5.0 V	High-Z
Program verify	Х	V _{IL}	+ 12.5 V	+6.5 V	D _{OUT}
Program	V _{IL}	V _{IH}	+ 12.5 V	+6.5 V	D _{IN}
Program inhibit	V _{IH}	V _{IH}	+ 12.5 V	+6.5 V	High-Z

Notes:

(1) "X" can be either V_{IL} or V_{IH} .

Block Diagram





Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Read Operation or Stand	iby				
Supply voltage	V _{CC}	4.5	5.0	5.5	V
	V _{PP}	V _{CC} - 0.6	Vcc	V _{CC} + 0.6	٧
Input voltage, high	V _{IH}	2.0		V _{CC} + 0.3	V
Input voltage, low	V _{IL}	-0.3		8.0	٧
Operating temperature	TA	0		70	°C
Programming Operation					
Supply voltage	Vcc	6.25	6.5	6.75	V
	V _{PP}	12.2	12.5	12.8	٧
Input voltage, high	V _{IH}	2.4		V _{CC} + 0.3	٧
Input voltage, low	V _{IL}	-0.3		0.8	٧
Operating temperature	TA	20	25	30	°C

DC Characteristics

 $T_A = 0 \text{ to } +70^{\circ}\text{C}; V_{CC} = +5.0 \text{ V} \pm 10\%; V_{PP} = V_{CC} \pm 0.6 \text{ V}$

Parameter	Symbol	Min	Тур	Max	Ųnit	Test Conditions
Read Operation, Outp	ut Disabled	, and Standby				
Output voltage, high	V _{OH1}	2.4			٧	I _{OH} = -400 μA
	V _{OH2}	V _{CC} - 0.7			٧	I _{OH} = -100 μA
Output voltage, low	V _{OL}			0.45	٧	I _{OL} = 2.1 mA
Output leakage current	lo	-10		10	μΑ	OE = V _{IH} ; V _{OUT} = 0 V to V _{CC}
input leakage current	ILI	-10		10	μА	V _{IN} = 0 V to V _{CC}
Operating supply current	I _{CCA1}			30	mA	CE = V _{IL} ; V _{IN} = V _{IH}
	ICCA2			30	mA	f = 6.7 MHz; l _{OUT} = 0 mA
Standby supply current	lccs1			1	mA	CE = V _{IH} min
	lccs2		1	100	μА	$\overline{CE} \ge V_{CC} - 0.2 \text{ V}; V_{IN} = 0 \text{ V to } V_{CC}$
Program voltage current	Грр		1	100	Αц	V _{PP} = V _{CC}

DC Characteristics (cont)

 $T_A = +25 \pm 5$ °C; $V_{CC} = +6.5 \text{ V} \pm 0.25$; $V_{PP} = +12.5 \text{ V} \pm 0.3$

Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Programming Operation	п					
Output voltage, high	V _{OH}	2.4	,		٧	I _{OH} = -400 μA
Output voltage, low	V _{OL}			0.45	٧	I _{OL} = 2.1 mA
input leakage current	l _{L1}	-10		10	μА	V _{IN} = 0 to V _{CC}
Operating supply current	lcc			30	mA	
Program voltage current	lpp			30	mA	CE = V _{IL} ; OE = V _{IH}



AC Characteristics

 $T_A = 0 \text{ to } +70^{\circ}\text{C}; V_{CC} = +5.0 \text{ V} \pm 10\%; V_{PP} = V_{CC}$

		μPD27C4001-15		μPD27C4001-17		μPD27C4001-20		•	
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Unit	Test Conditions (Note 1)
Read Operation and Standby									
Address to output delay	t _{ACC}		150		170		200	ns	CE = OE = VIL
CE to output delay	tCE		150		170		200	ns	ŌĒ = V _{IL}
OE to output delay	toE		70		70		75	ns	CE = V _{IL}
OE or CE to data output float delay	t _{DF}	0	55	0	55	0	60	ns	CE = V _{IL} or OE = V _{IL}
Address to output hold time	t _{OH}	0		0		0		ns	CE = OE = VIL

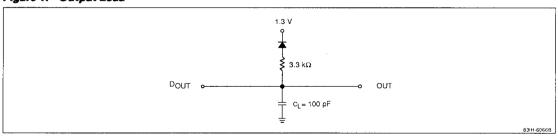
AC Characteristics (cont) $T_A = +25 \pm 5^{\circ}C$; $V_{CC} = +6.5 \text{ V} \pm 0.25$; $V_{PP} = +12.5 \text{ V} \pm 0.3$

Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions (Note 1)
Programming Operation						
Address setup time	t _{AS}	2			μs	
OE setup time	toes	2			μs	
Data setup time	t _{DS}	2			μѕ	
Address hold time	t _{AH}	2			μS	
Data hold time	t _{DH}	2			μs	
Output enable to output float delay	t _{DF}	0		130	ns	
V _{PP} setup time	tvps	2			μѕ	
Program pulse width	t _{PW}	0.095	0.1	0.105	ms	
V _{CC} setup time	tvcs	2			μs	
Data valid from OE	toE			150	ns	

Notes:

(1) Inputs levels = 0.45 to 2.4 V; input and output timing reference levels = 0.8 V and 2.0 V; input rise and fall times \leq 20 ns. See figure 1 for output load.

Figure 1. Output Load





PROGRAMMING OPERATION

Begin programming by erasing all data; this sets all bits at a high logic level. The μ PD27C4001 is originally shipped in this condition. To enter data, apply valid data at the eight output pins of the chosen address. Raise V_{CC} to +6.5 V ±0.25 ; then raise V_{PP} to +12.5 V ±0.3 .

 $\overline{\text{OE}}$ should be set high to to start programming the initial address. Apply a 0.1-ms program pulse to $\overline{\text{CE}}$ as shown in the programming portion of the timing waveforms. Set $\overline{\text{OE}}$ low to verify the eight bits prior to making a program/no program decision. If the address is not programmed, apply another 0.1-ms pulse to $\overline{\text{CE}}$, up to a maximum of 10 times, and input the next address. If the bits are not programmed in 10 tries, reject the device as a program failure. After all addresses are programmed, lower Vpp and then VCC to $+5.0 \text{ V} \pm 10\%$ and verify all data again.

Program Inhibit

This option is used to program multiple $\mu PD27C4001s$ connected in parallel. All like inputs except \overline{CE} and \overline{OE} may be common. Program individual devices by applying a high level to all \overline{OE} pins and a low-level TTL pulse to the \overline{CE} pin of the device to be programmed. Applying a high-level signal to the \overline{CE} pins of the other devices prevents them from being programmed.

Program Verification

To verify that the device is correctly programmed, normal read cycles can be executed with a high logic level applied to all $\overline{\text{CE}}$ pins and a low logic level applied to the $\overline{\text{OE}}$ pin of the device to be verified. A high logic level should be applied to the $\overline{\text{OE}}$ pins of all other devices.

Program Erasure

Erase data on the μ PD27C4001 by exposing it to light with a wavelength shorter than 400 nm. Since exposure to direct sunlight or room-level fluorescent light could also erase the data, mask the window to prevent unintentional erasure by ultraviolet rays. Opaque labels are supplied with every device.

Data is typically erased by ultraviolet rays with a wavelength of 254 nm. A minimum integrated dose of 15 W-sec/cm² (ultraviolet lighting intensity multiplied by exposure time) is required to completely erase written data.

An ultraviolet lamp rated at $12,000~\mu\text{W/cm}^2$ takes approximately 20 minutes to complete erasure. Place the $\mu\text{PD27C4001}$ within 2.5 cm of the lamp tubes and remove any filter on the lamp.



Timing Waveforms

Programming Cycle

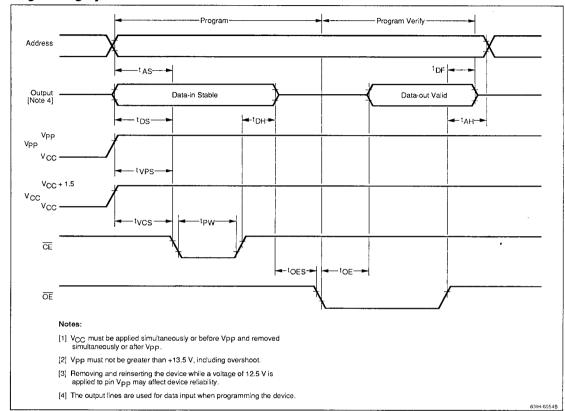
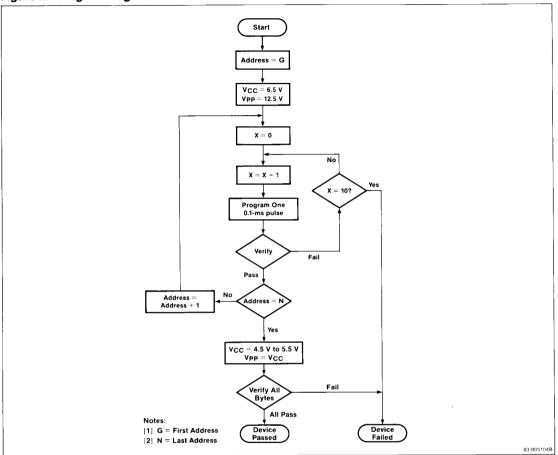




Figure 2. Programming Flowchart





Timing Waveforms (cont)

Read Cycle

